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Stand-off filament-induced ablation of gallium arsenide

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Using femtosecond filaments for the ablation of GaAs in air, we have observed that the diameter and volume of the resulting ablation craters remained almost constant with propagation distance. This constant mass removal along the propagation of a filament in both focused and non-focused configurations is valuable for applications such as material processing and stand-off laser-ablation based spectroscopy. © 2012 American Institute of Physics. [<http://dx.doi.org/10.1063/1.4734497>]

Filamentation of femtosecond laser pulses in air was first observed in 1995¹ and has enabled applications, such as remote spectroscopy,^{2–4} laser material processing,^{5–7} filament-induced laser machining (FILM),⁸ and lightning control.^{9–13} Filamentation occurs when the input laser power exceeds a critical power threshold of 3.2 GW in air for 100 fs pulses at 800 nm.¹⁴ Because the distance required for the onset of filamentation is usually on the order of several meters, depending on pulse characteristics, a lens is often used to help the collapse of the pulse.

Filaments have been shown to have the following characteristics: a central core diameter on the order of 100 μm with an irradiance¹ on the order of 10^{13} W/cm^2 that contains 5%–10% of the total energy^{15,16}—depending on the initial beam size and energy¹⁶—and an energy reservoir that is more than 5 times the diameter of the core and contains approximately 50% of the beam energy.¹⁷ The filament core and energy reservoir are further surrounded by the less intense portion of the beam that contains the remaining energy. In contrast to focused femtosecond Gaussian beams, filaments present a unique irradiance profile, negligibly small numerical aperture and temporal pulse compression^{18–21} with potential temporal pulse splitting^{22,23} and steepening.^{24,25} These unique attributes of filamentation could lead to differences in laser material interaction and the resulting ablation.

This study aims to characterize the ablation of gallium arsenide (GaAs) by a single laser filament for remote applications such as laser-ablation-based spectroscopy and material processing. The reason for using GaAs was three-fold: (i) the interaction of femtosecond laser radiation with GaAs has been the topic of investigation since before laser filamentation in air was first reported,^{26–29} (ii) GaAs provided a smooth substrate that allowed for the characterization of single shot phenomena, and (iii) the slow rate of surface oxidation on GaAs has been characterized.³⁰ For a GaAs sample ablated using a laser filament, we have compared the effects of focus-assisted filamentation, which are better known, with non-focused long distance filamentation which can be used for stand-off applications. We have found that the diameter and ablated crater volume remained fairly constant for both focused and non-focused filamentations within 12 m and 50 m ranges, respectively.

Filaments were generated using a commercial Ti:Sapphire CPA laser system (*Tsunami + Spitfire*, Spectra Physics) operated at 10 Hz and capable of producing 25 mJ pulses measured with a pyroelectric energy meter (*QE-25 + Solo II*, Gentec), with a pulse duration of 45 fs measured by FROG (*Model 8–20*, Swamp Optics).³¹ This system was used to generate filaments within a 12 m range and a 50 m range. Within the 12 m range, the laser was operated with minimal chirp at 7.6 ± 0.2 mJ pulse energy. Filaments were generated along a 6.6 m optical rail using a 10 m focal length dielectric mirror that was illuminated 1° off-axis. Within the 50 m range, 21.5 mJ pulse energy was used (3.7% RMS and 21.5% PTP (peak to peak) fluctuations) without external focusing optics. The pulses were chirped, by detuning the compressor, to prevent the onset of filamentation until after the beam steering optics. The initial pulse duration was approximately 500 fs. This was estimated by comparing the semi-empirical formula for propagation distance required for collapse^{14,32,33} and the distance for the beam to start filamenting, because it was outside the measureable range of our FROG (i.e., more than 180 fs).

The samples utilized were double-side-polished non-doped GaAs (1 0 0) wafers (ATX, Inc.) mounted with the surface perpendicular to the filamentation axis. In each sample position, a single filament was used for ablation and the sample was translated to a fresh surface for the next ablation; therefore, at each axial position along the filament, ablation statistics could be determined over 15 independent shots.

Sample metrology was performed primarily using an optical microscope (*BX-51*, Olympus) and a white-light interferometric microscope (WIM) (*Newview 6300*, Zygo). The optical surface profilometry results were verified using a surface contact profilometer (*AlphaStep 200*, Tencor).

The ablation crater on GaAs that resulted from femtosecond-filament irradiation (Fig. 1) had a diameter of approximately 470 μm . The sharp crater edges were characteristic of the femtosecond ablation of semiconductors³⁴ and the crater presented little debris or heat influenced zones. Crater analysis using WIM, with micron transverse resolution limited by $10\times$ optical objective and nanometer depth resolution, allowed for the retrieval of crater diameter and volume. When ablated by the filament within the 12 m range, the diameter and volume of the resulting craters remained

FIG. 1. 3D representation of an ablation crater, measured using WIM. The ablation crater resulted from a single shot at a distance of 15 m and without external focusing. False colormap represents the crater depth (linear scale).

constant (Fig. 2). The average crater diameter was $412 \mu\text{m}$ with 5.1% relative standard deviation (RSD) and crater volume was $7600 \mu\text{m}^3$ with 6.8% RSD. Samples were ablated every 40 cm, for sample-to-focusing-mirror distances between 5.2 m and 12.8 m. Under these conditions, the evolution of filamentation was clearly apparent. Filamentation occurred from approximately 6 m up to 11 m, measured with respect to the focusing mirror; therefore, filamentation initiated by focusing ($f = 10$ m) resulted in constant ablation well beyond the Rayleigh range.

Within the 50 m range (Fig. 3), no external focusing optics were used and, therefore, filamentation resulted from self-focusing alone. Distances were measured with respect to the last beam steering mirror, approximately 5 m from the laser output. Shot-to-shot fluctuations in the location of filament formation/discontinuation along the axis, coupled with shot-to-shot energy fluctuations and turbulence along the propagation resulted in larger error bars (Fig. 3) when com-

FIG. 2. Results from 12 m range: (a) Filament induced ablation crater diameter as a function of distance. (b) Ablated volume as a function of distance. Error bars represent the standard deviation evaluated over 15 measurements.

FIG. 3. Results from 50 m range: (a) Diameter of filament induced ablation crater as a function of distance. (b) Ablated volume as a function of distance. Error bars evaluated over 15 measurements.

pared with the focus-assisted-filamentation within the 12 m range (Fig. 2). Non-focused filamentation resulted in craters with an average diameter of $410 \mu\text{m}$ with 27% RSD and volume of $5800 \mu\text{m}^3$ with 45% RSD. The small decrease in crater volume for non-focused filamentation (Fig. 3(b)) versus focus-assisted-filamentation (Fig. 2(b)) suggests an irradiance difference between focused and non-focused configurations and is consistent with the previously reported dependence of filament plasma density and modeled fluence on lens focal length.³⁵ However, over a propagation distance of 35 m (Fig. 3), the crater diameter and volume remained quite constant, and the ablative power was remarkably similar to controlled filamentation using external focusing within a laboratory environment (Fig. 2).

For 100 fs pulses, the ablation threshold of crystalline GaAs has commonly been reported^{36,37} as between 175 mJ/cm^2 and 214 mJ/cm^2 . In both filamentation conditions presented here, 50 m range non-focused and 12 m range focus-assisted filamentation, the ablation craters were larger in diameter than the approximately $100 \mu\text{m}$ filament core.^{1,33} This suggests that the energy reservoir (region surrounding the filament) also exceeded the ablation threshold and remained constant during the filamentation process. These experimental observations agree with simulations³⁸ for the filament fluence at radial distances of a few hundred microns, reported as being greater than 170 mJ/cm^2 . Therefore, the energy reservoir should also be considered for filament induced ablation.

For focus-assisted filamentation, the crater volume remained approximately constant at $7600 \mu\text{m}^3$ over 5 m of propagation and for non-focused filamentation, the crater volume remained about $5800 \mu\text{m}^3$. As the density of GaAs is

5.136 g/cm³, the removed mass within these two regimes was about 39 ng and 30 ng, respectively.³⁹ For stand-off chemical analysis using filamentation, material sampling on the order of 30 ng is within the usable range for atomic emission spectroscopy.⁴⁰

In conclusion, we have presented a quantitative comparison between focus assisted filamentation over a range of 12 m and non-focused filamentation over a 50 m range. We have shown that in both cases the ablation was similar. The importance of the energy reservoir in the interaction of laser filamentation with materials was clearly demonstrated by the formation of craters with larger diameter than the filament core.

Within the regime of non-focused filamentation, which has previously been reported for propagation over kilometer distances, this quasi constant material sampling with each shot should have important implications for stand-off spectroscopy and material processing applications.

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